



566.40894X00

**EXPEDITED PROCEDURE PURSUANT  
TO 37 CFR §1.116 REQUESTED**

#18  
Amended  
J. H. H.  
9-25-03

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Applicants: K. HORIKOSHI et al  
Serial No.: 09/988,585  
Filed: November 20, 2001  
For: THIN-FILM TRANSISTOR AND METHOD OF  
MANUFACTURING THE SAME  
Group: 2811  
Examiner: T. TRAN

**AMENDMENT AFTER FINAL**

**MS: After Final**

Commissioner For Patents  
POB 1450  
Alexandria, VA 22313-1450

June 27, 2003

RECEIVED  
JUN 30 2003  
TECHNOLOGY CENTER 2800

Sir:

In response to the Final Office Action, dated February 27, 2003, the period of response for which extension of time is requested in the attached Petition for Extension of Time, the following amendments and remarks are respectfully submitted in connection with the above-identified application.

**IN THE CLAIMS:**

Please **cancel** claim 2 without prejudice or disclaimer and **amend** claims 1 and 9 to read as follows:

1. (Twice Amended) A thin-film transistor comprising:  
a glass substrate; and